

PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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10/549621

In re application of:

Dirk BREIDT *et al.*

Serial No: TBA

Filed: September 20, 3005

For: Body Having A Smooth Diamond Layer,
Device And Method Therefor

Group Art No. TBA

Examiner: TBA

Docket No. 000475.00012

INFORMATION DISCLOSURE STATEMENT

Commissioner of Patents
U.S. Patent and Trademark Office
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Randolph Building
401 Dulany Street
Alexandria, VA 22314

Sir:

Pursuant to 37 C.F.R. §1.56 and in compliance with 37 C.F.R. §1.97, Applicants submit herewith one Form PTO-1449 identifying information for consideration by the Examiner.

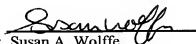
Copies of the cited documents were provided with the International Search Report for the corresponding PCT application.

If the Patent and Trademark Office determines that a fee is required, please charge our Deposit Account No. 19-0733.

Respectfully submitted,

BANNER & WITCOFF, LTD.

Date: 9/19/05

By: 
Susan A. Wolffe
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SAW/sdm

USPTO Form 1449 U.S. Department of Commerce Patent and Trademark Office INFORMATION DISCLOSURE CITATION Sheet 1 of 1		<div style="text-align: right; font-size: 1.2em; font-weight: bold;">10/549621</div> Attorney Docket No. 000475.00012				
		Applicant(s): Dirk BREIDT et al Filing Date: September 20, 2005				
		Group: TBA				
U.S. PATENT DOCUMENTS						
Examiner Initial	Patent No.	Date	Name	Class	Subclass	Filing Date (if appropriate)
	US 5 567 522 A	22 October 1996	TAKAHASHI, T et al.			
FOREIGN PATENT DOCUMENTS						
Examiner Initial	Document No.	Date	Country	Class	Subclass	Translation
	DE 199 22 665 A	23 November 2000	Germany			YES NO
	WO 01/48284 A	15 March 2001	PCT			
OTHER DOCUMENTS (including Author, Title, Date, Pertinent Pages, etc.)						
ALI et al.: "Promoting secondary nucleation using methane modulations during diamond chemical vapor deposition to produce smoother, harder, and better quality films", J. MATER. RES. (USA) JOURNAL OF MATERIALS RESEARCH, Feb 2003, Vol. 18, No. 2, pages 296-304, XP009034569.						
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FAN et al.: "Novel time-modulated chemical vapor deposition process for growing diamond films", J. MATER. RES. (USA) JOURNAL OF MATERIALS RESEARCH, July 2002, vol. 17, no. 7, pages 1563-1566, XP009034570.						
LEE et al.: "Cyclic technique for the enhancement of highly oriented diamond film growth", THIN SOLID FILMS, vol. 303, no. 1-2, July 15, 1997, pages 264-268, XP004087644.						
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CHEN et al.: "Growth of Highly Transparent Nanocrystalline Diamond Films and a Spectroscopic Study of the Growth", JOURNAL OF APPLIED PHYSICS, vol. 83, no. 1, January 1, 2001, pages 753-759, XP001053812.						
JIANG et al.: "Synthesis and structural study of nano/micro diamond overlayers films", JOURNAL OF CRYSTAL GROWTH, vol. 242, no. 3-4, July 2002, pages 362-366, XP004368868.						
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ALI et al.: "Implementation of the time-modulated process to produce diamond films using microwave-plasma and hot filament CVD systems", VACUUM (UK) July 25, 2003, vol. 71, no. 4, pages 445-450, XP002290488.						
EXAMINER				DATE CONSIDERED		
/Matthew Song/				05/09/2009		
<small>*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.</small>						